

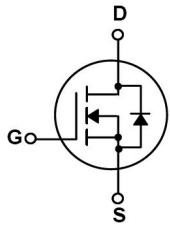
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TO-220      N      MOS      N-CHANNEL MOSFET in a TO-220 Plastic Package.

Low gate charge, low crss, fast switching.

DC/DC

These devices are well suited for high efficiency switching DC/DC converters .



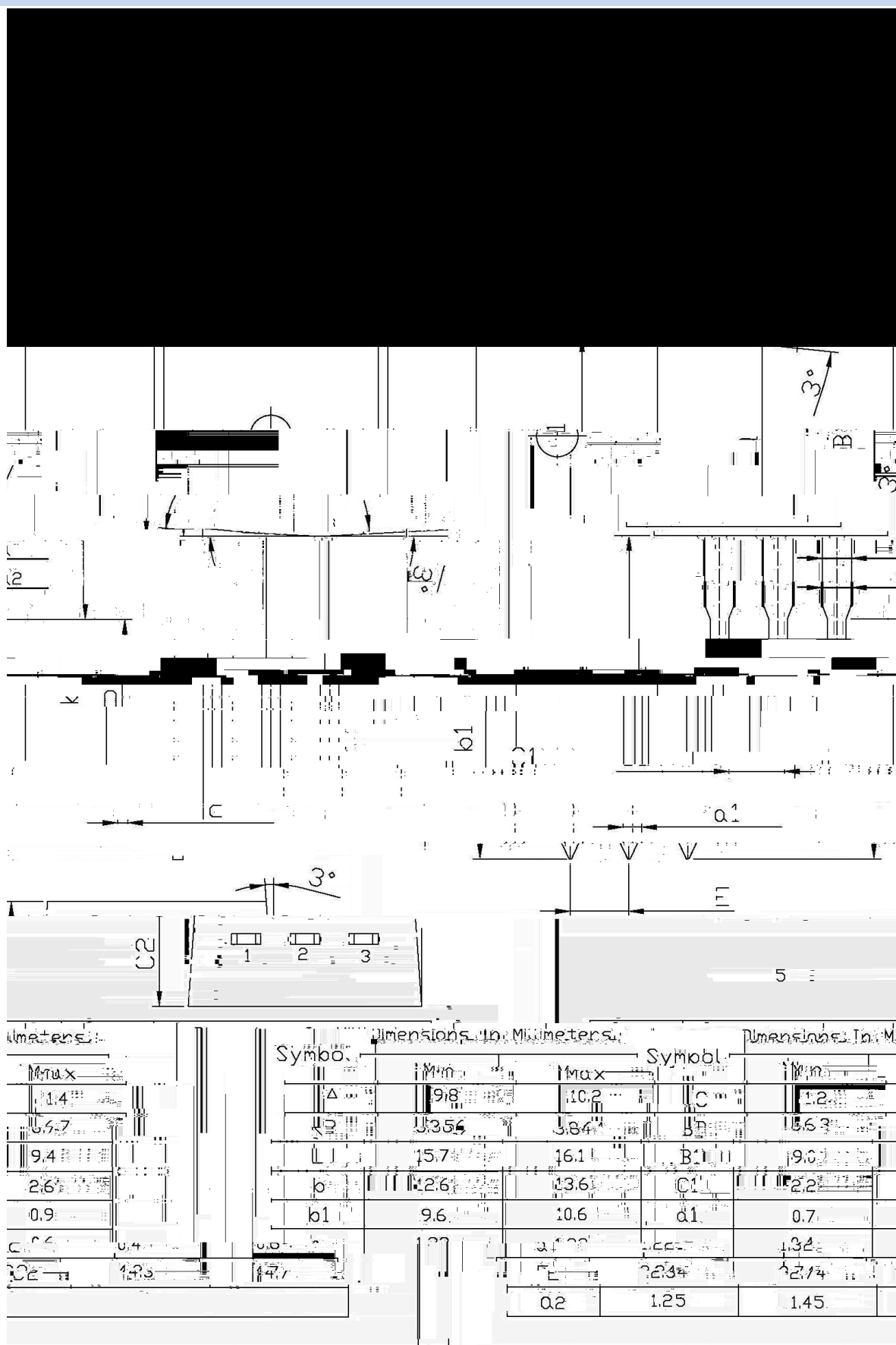
PIN1   G      PIN 2   D      PIN 3   S

See Marking Instructions.

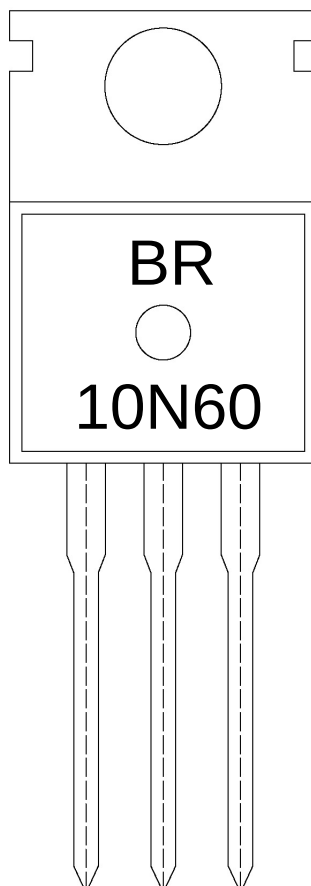
| Parameter                               | Symbol                       | Rating     | Unit |
|-----------------------------------------|------------------------------|------------|------|
| Drain-Source Voltage                    | $V_{DSS}$                    | 600        | V    |
| Drain Current                           | $I_D(T_c=25^\circ\text{C})$  | 9.5        | A    |
| Drain Current                           | $I_D(T_c=100^\circ\text{C})$ | 5.7        | A    |
| Drain Current - Pulsed                  | $I_{DM}$                     | 38         | A    |
| Gate-Source Voltage                     | $V_{GSS}$                    | $\pm 20$   | V    |
| Single Pulsed Avalanche Energy          | $E_{AS}$                     | 700        | mJ   |
| Repetitive Avalanche Energy             | $E_{AR}$                     | 15.6       | mJ   |
| Avalanche Current                       | $I_{AR}$                     | 9.5        | A    |
| Thermal Resistance, Junction to Case    | $R_{\theta JC}$              | 0.8        | /W   |
| Thermal Resistance, Junction to Ambient | $R_{\theta JA}$              | 62.5       | /W   |
| Power Dissipation                       | $P_D(T_c=25^\circ\text{C})$  | 156        | W    |
| Operating and Storage Temperature Range | $T_J, T_{STG}$               | -55 to 150 |      |

| Parameter                          | Symbol       | Test Conditions                            | Min | Typ  | Max       | Unit     |
|------------------------------------|--------------|--------------------------------------------|-----|------|-----------|----------|
| Drain-Source Breakdown Voltage     | $BV_{DSS}$   | $V_{GS}=0V$ $I_D=250\mu A$                 | 600 |      |           | V        |
| Zero Gate Voltage Drain Current    | $I_{DSS}$    | $V_{DS}=600V$ $V_{GS}=0V$                  |     |      | 1         | $\mu A$  |
|                                    |              | $V_{DS}=480V$ $T_C=125^\circ\text{C}$      |     |      | 100       | $\mu A$  |
| Gate-Body Leakage Current Forward  | $I_{GSS}$    | $V_{GS}=\pm 20V$ $V_{DS}=0V$               |     |      | $\pm 100$ | nA       |
| Gate Threshold Voltage             | $V_{GS(th)}$ | $V_{DS}=V_{GS}$ $I_D=250\mu A$             | 2.0 |      | 4.0       | V        |
| Static Drain-Source On-Resistance  | $R_{DS(on)}$ | $V_{GS}=10V$ $I_D=4.75A$                   |     | 0.6  | 0.73      | $\Omega$ |
| Forward Transconductance           | $g_{FS}$     | $V_{DS}=40V$ $I_D=4.75A$                   |     | 8.0  |           | S        |
| Drain-Source Diode Forward Voltage | $V_{SD}$     | $V_{GS}=0V$ $I_S=9.5A$                     |     |      | 1.4       | V        |
| Total Gate Charge                  | $Q_g$        | $I_D=10A$ $V_{DS}=480V$<br>$V_{GS}=10V$    |     | 45   |           | nC       |
| Gate-to-Source Charge              | $Q_{gs}$     |                                            |     | 7.5  |           | nC       |
| Gate-to-Drain Charge               | $Q_{gd}$     |                                            |     | 18.5 |           | nC       |
| Input Capacitance                  | $C_{iss}$    | $V_{DS}=25V$ $V_{GS}=0V$<br>$f=1.0MHz$     |     | 1570 | 2040      | pF       |
| Output Capacitance                 | $C_{oss}$    |                                            |     | 166  | 215       | pF       |
| Reverse Transfer Capacitance       | $C_{rss}$    |                                            |     | 18   | 24        | pF       |
| Turn-On Delay Time                 | $t_{d(on)}$  | $V_{DD}=300V$ $I_D=9.5A$<br>$R_G=25\Omega$ |     | 23   | 55        | ns       |
| Turn-On Rise Time                  | $t_r$        |                                            |     | 69   | 150       | ns       |
| Turn-Off Delay Time                | $t_{d(off)}$ |                                            |     | 144  | 300       | ns       |
| Turn-Off Fall Time                 | $t_f$        |                                            |     | 77   | 165       | ns       |





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BR

10N60

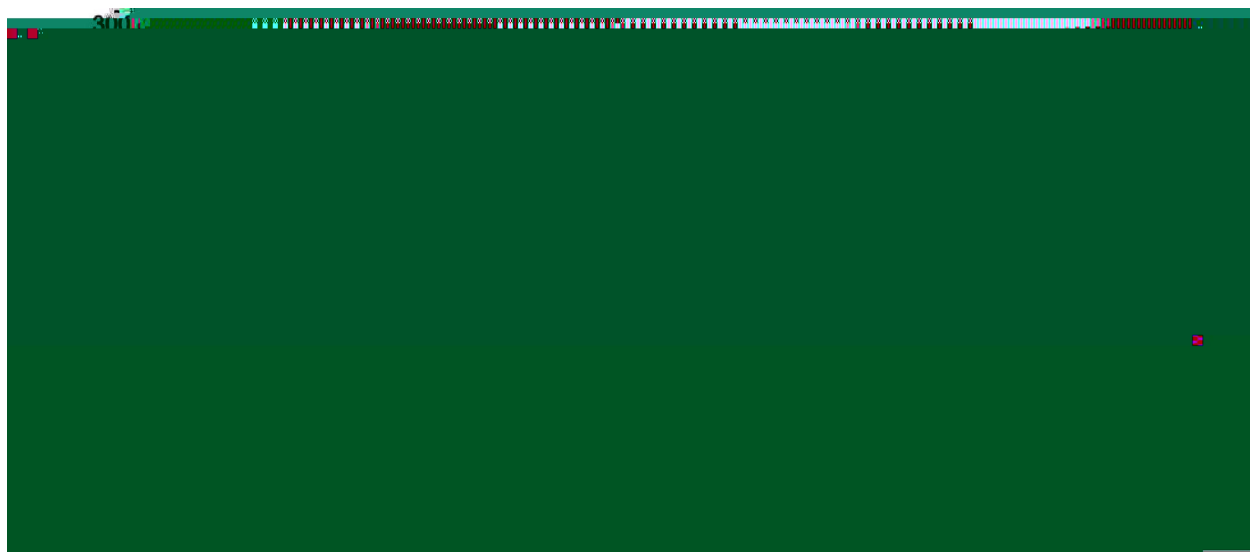
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Note:

BR: Company Code

10N60: Product Type Code.

\*\*\*\*: Lot No. Code, code change with Lot No.



Note:

- |   |       |     |           |        |                                         |
|---|-------|-----|-----------|--------|-----------------------------------------|
| 1 | 25    | 150 | 60        | 90sec; | 1.Preheating:25~150 , Time:60~90sec.    |
| 2 | 255±5 |     | 5±0.5sec; |        | 2.Peak Temp.:255±5 , Duration:5±0.5sec. |
| 3 |       | 2   | 10        | /sec.  | 3. Cooling Speed: 2~10 /sec.            |

270±5

10±1 sec.

Temp.:270±5

Time:10±1 sec

/ BULK

| Package Type | Units |  |  |  |  | Dimension |  | (unit mm <sup>3</sup> ) |
|--------------|-------|--|--|--|--|-----------|--|-------------------------|
|              |       |  |  |  |  |           |  |                         |
|              |       |  |  |  |  |           |  |                         |

/ TUBE

| Package Type | Units |  |  |  |  | Dimension |  | (unit mm <sup>3</sup> ) |
|--------------|-------|--|--|--|--|-----------|--|-------------------------|
|              |       |  |  |  |  |           |  |                         |
|              |       |  |  |  |  |           |  |                         |